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Electronic Supplementary Information

Solvothermal Synthesis of Wire-Like Sn_xSb₂Te_{3+x} with Enhanced Thermoelectric Performance

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The Preparation of Elemental Sb and Te Precursors:

Hydrothermal route for the synthesis of elemental Sb precursor. 12 g of SbCl₃ was firstly dissolved into 20 ml of EG, and then 200ml of ~ 1.9 mol L⁻¹ NaOH solution and 20 ml of ~ 5.3 mol L⁻¹ of NaBH₄ solution were added successively under stirring. Finally, the mixture was transferred into a 500-ml-capacity Teflon-lined stainless-steel autoclave and filled up to about 80% of its total volume. It was maintained at 150 °C for 12 h and then cooled to room temperature naturally. The product was collected after washing and drying.

Reflux method for the synthesis of elemental Te precursor. 12 g of TeO₂ and 300 ml of EG were added into a 500 ml one-neck flask. Then it was put on a mantle and maintained at 180 °C for about 30 min to form a transparent solution. 15 ml of N_2H_4 · H_2O was added into the above solution after it cooled down below 100 °C. Finally, the mixture was refluxed at 120 °C for 12 h. The product was collected after washing and drying.



Fig. S1 XRD patterns and SEM images of as-synthesized elemental Sb and Te precursors: (a,b,c) Sb; (d,e,f) Te. The orange and wine bars stand for the standard XRD pattern of Sb (JCPDS 085-1322) and Te (JCPDS 078-2312), respectively.



Fig. S2 (a) XRD pattern of the SnTe powder synthesized at 120 °C for 24 h. The blue bars stand for the standard XRD pattern of SnTe (JCPDS 065-7162) and the black solid square (■) stands for Te. (b–d) SEM images of as-synthesized SnTe powder.



Fig. S3 SEM images of the as-sintered Sb_2Te_3 (a,b), $Sn_{0.02}Sb_2Te_{3.02}$ (c,d) and $Sn_{0.05}Sb_2Te_{3.05}$ (e,f) bulk samples.



Fig. S4 The repeated measurement of temperature dependent resistivity (a) and Seebeck coefficient (b) and calculated power factor (c) on the Sb_2Te_3 nanobulk sample.



Fig. S5 The measured specific heat (C_p) and thermal diffusivity (λ) of Sb₂Te₃ and Sn_xSb₂Te_{3+x} (x = 0.02 and 0.05) samples: (a) C_p ; (b) λ .



Fig. S6 The calculated Lorenz number (*L*) of Sb_2Te_3 and $Sn_xSb_2Te_{3+x}$ (x = 0.02 and 0.05) samples.